SILICON (Si) POWER MOSFET A CEM0515L



CEM0515L

150V ▲ 63mΩ ▲ 4.3A ▲ Si MOSFET

SILICON Si MOSFET ▲ SMD type N-channel enhancement mode UL94V-0 rated flame retardant epoxy SO8 package ▲ MSL 3 Super high dense cell density for extremely low R_{DS(ON)} High power and current handling capability

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MAXIMUM RATINGS

| Parameter (T _A = 25°C, unless otherwise noted) | Characteristics | |
|---|-----------------------------------|-----------------|
| Drain-Source Voltage | V _{DS} | 150V |
| Gate-Source Voltage | V _{GS} | ±20V |
| Continuous Drain Current | I _D | 4.3A |
| Pulsed Drain Current Note 1 | I _{DM} | 17.2A |
| Maximum Power Dissipation | PD | 2.5W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55°C to +150°C |

THERMAL CHARACTERISTICS

| Parameter | Symbol | Limit |
|--|--------------------|--------|
| Thermal Resistance, Junction-to-Ambient Note 2 | R _{TH_JA} | 50°C/W |

APPLICATIONS

| Audio | Industrial | Power over | Power | UPS |
|-------------|------------|------------|----------|-----|
| Amplifier | Control | Ethernet | Inverter | |
| ()) | | PoE | | |

PIN DESCRIPTION

| | | Description |
|----------------|--------|---|
| | 1 | Source |
| | 2 3 | Source Source |
| | 4 | Gate Drain |
| | 6 | Drain |
| H H H 2 3 4 | 7 | Drain Drain |
| | | A A A A 3 4 5 6 H H H H H H |

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HALOGEN

FREE





CET MOS

ELECTRICAL CHARACTERISTICS A T_A = 25°C, unless otherwise noted

| Item | Condition | Symbol | Min. | Тур. | Max. | Unit |
|---|--|---------------------|------|------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V$, $I_D = 250\mu A$ | BV _{DSS} | 150 | | | V |
| Zero Gate Voltage Drain Current | V_{DS} = 150V, V_{GS} = 0V | I _{DSS} | | | 1 | μΑ |
| Gate Body Leakage Current, Forward | $V_{GS} = 20V$, $V_{DS} = 0V$ | I _{GSSF} | | | 100 | nA |
| Gate Body Leakage Current, Reverse | V_{GS} = -20V, V_{DS} = 0V | I _{GSSR} | | | -100 | nA |
| On Characteristics Note 3 | | | | | | |
| Gate Threshold Voltage | $V_{GS} = V_{DS}$, $I_D = 250 \mu A$ | V _{GS(th)} | 1 | | 3 | V |
| Static Drain-Source On-Resistance | $V_{GS} = 10V, I_{D} = 5A$ | R _{DS(ON)} | | 63 | 75 | mΩ |
| Static Drain-Source On-Resistance | V_{GS} = 4.5V, I_D = 4A | R _{DS(ON)} | | 70 | 88 | mΩ |
| Dynamic Characteristics Note 4 | | | | | | |
| Input Capacitance | V_{DS} = 75V, V_{GS} = 0V, f = 1MHz | C _{ISS} | | 625 | | pF |
| Output Capacitance | $V_{DS} = 75V, V_{GS} = 0V, f = 1MHz$ | Coss | | 95 | | pF |
| Reverse Transfer Capacitance | V_{DS} = 75V, V_{GS} = 0V, f = 1MHz | C _{RSS} | | 25 | | pF |
| Switching Characteristics Note 4 | | | | | | |
| Turn-On Delay Time | V_{DD} = 75V, V_{GS} = 10V, I_D = 1A, $R_{G(ext)}$ = 10 Ω | t _{D(ON)} | | 14 | | ns |
| Turn-On Rise Time | V_{DD} = 75V, V_{GS} = 10V, I_D = 1A, $R_{G(ext)}$ = 10 Ω | t _R | | 7 | | ns |
| Turn-Off Delay Time | V_{DD} = 75V, V_{GS} = 10V, I_D = 1A, $R_{G(ext)}$ = 10 Ω | t _{D(OFF)} | | 35 | | ns |
| Turn-Off Fall Time | V_{DD} = 75V, V_{GS} = 10V, I_D = 1A, $R_{G(ext)}$ = 10 Ω | t _F | | 14 | | ns |
| Total Gate Charge | V_{DS} = 75V, V_{GS} = 10V, I_D = 5A | Q _G | | 14.6 | | nC |
| Gate Source Charge | V_{DS} = 75V, V_{GS} = 10V, I_D = 5A | Q _{GS} | | 1.5 | | nC |
| Gate Drain Charge | V_{DS} = 75V, V_{GS} = 10V, I_{D} = 5A | \mathbf{Q}_{GD} | | 5.4 | | nC |
| Drain-Source Diode Characteristics a | nd Maximum Ratings | | | | | |
| Drain-Source Diode Forward Current ^{Note 2} | | ١ _s | | | 2 | А |
| Drain-Source Diode Forward Voltage ^{Note 3} | V _{GS} = 0V, I _S = 5A | V_{SD} | | | 1.2 | V |

Notes

1: Repetitive Rating: Pulse width limited by maximum junction temperature

2: Surface Mounted on FR4 Board, $t \le 10$ sec

3: Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

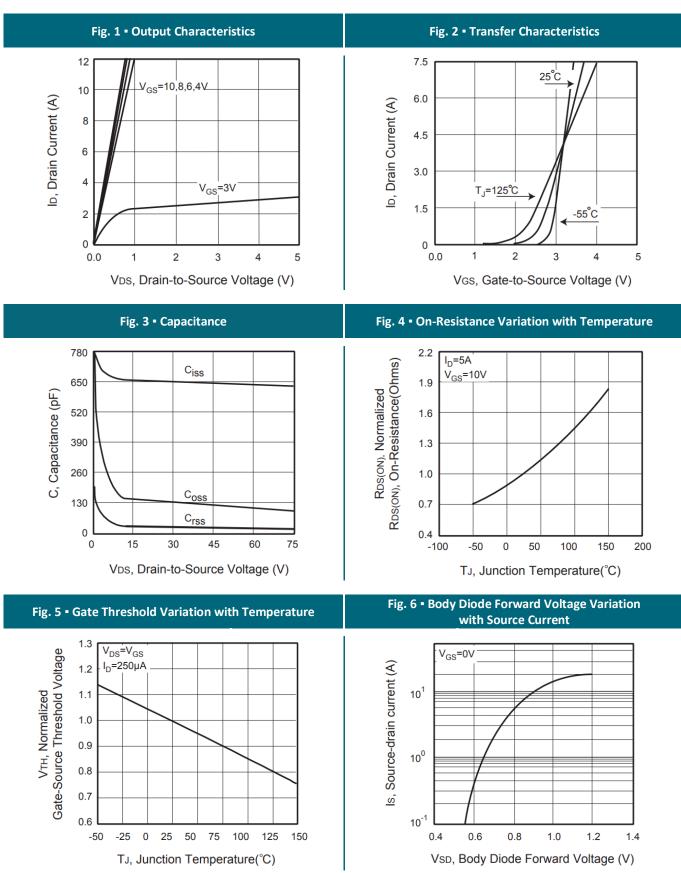
4: Guaranteed by design, not subject to production testing.



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REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE



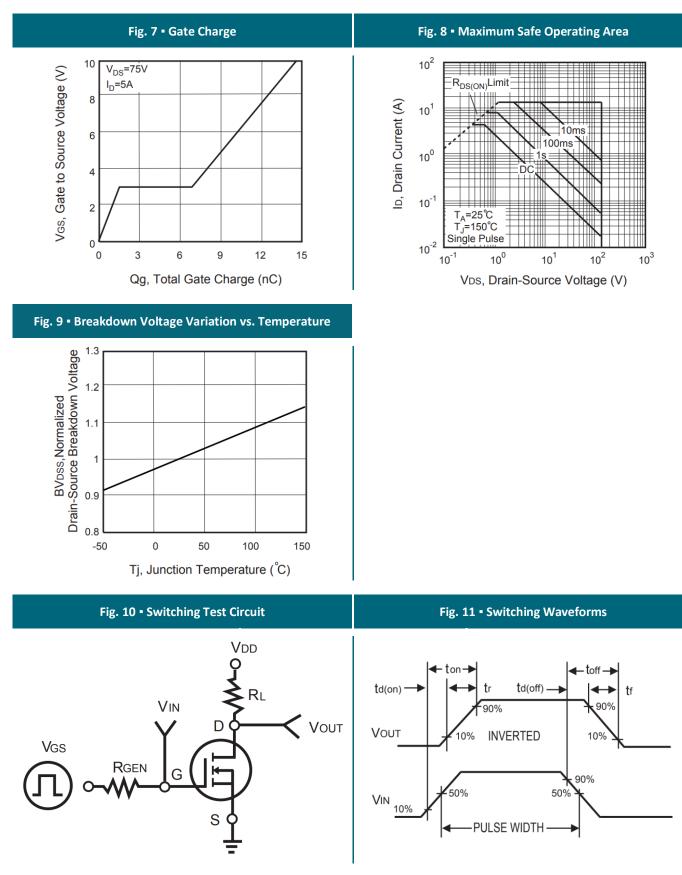
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REFERENCE DATA A TYPICAL DEVICE PERFORMANCE



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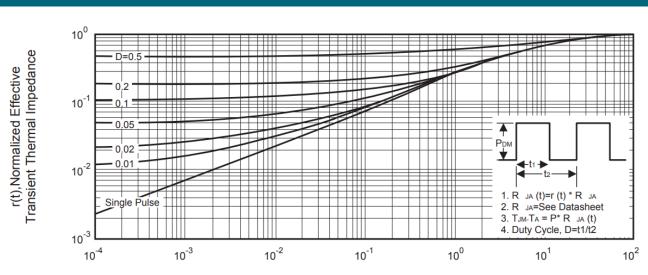
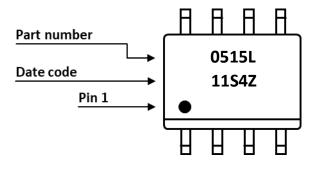


Fig. 12 • Normalized Thermal Transient Impedance Curve

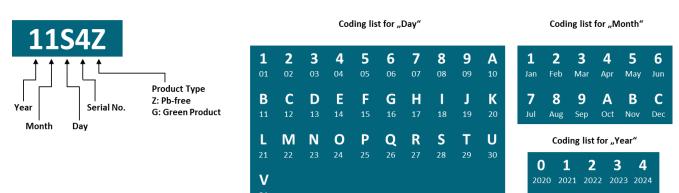
Square Wave Pulse Duration (sec)

PART MARKING



DATE CODE

Example: 11S4Z



8 9

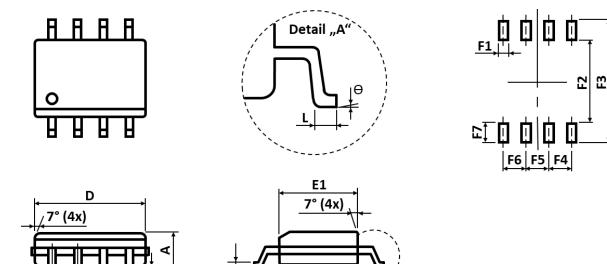
7 2025 2026 2027 2028 2029

5 6

• Detail "A"



PACKAGE OUTLINE AND RECOMMENDED PAD LAYOUT



| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) | Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|-----------------------|-----------------------|-----------------------|-----|-----------------------|-----------------------|-----------------------|
| А | 1.350 | - | 1.750 | E1 | 3.700 | | 4.060 |
| A1 | 0.100 | - | 0.250 | eB | 5.800 | | 6.200 |
| В | 0.310 | - | 0.510 | е | | 1.270 | |
| С | 0.170 | - | 0.250 | L | 0.400 | | 0.950 |
| D | 4.690 | - | 5.000 | θ | 0° | - | 8° |
| | | | | | | | |
| Sym | Millimeters | Millimeters | Millimeters | Svm | Millimeters | Millimeters | Millimeters |

eВ

| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) | Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) | |
|-----|-----------------------|-----------------------|-----------------------|-----|-----------------------|-----------------------|-----------------------|--|
| | | | | | | | | |
| F1 | - | 0.500 | - | F5 | - | 1.270 | - | |
| F2 | - | 4.250 | - | F6 | - | 1.270 | - | |
| F3 | - | 6.250 | - | F7 | - | 1.000 | - | |
| F4 | - | 1.270 | - | | | | | |

Notes: 1. The suggested land pattern dimensions have been provided for reference only. 2. For further information, please reference document IPC-7351A.

C

ORDERING INFORMATION

В

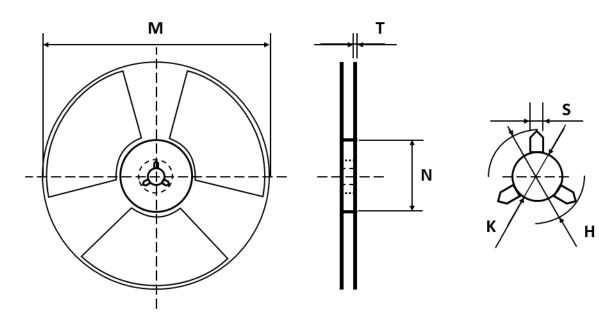
A1

| Part Number | Package | Packing | Reel Qty. | Inner Box Qty. | Outer Box Qty. |
|-------------|---------|----------|-----------|----------------|----------------|
| CEM0515L | SO8 | 13" Reel | 2,500pcs | 5,000pcs | 40,000pcs |



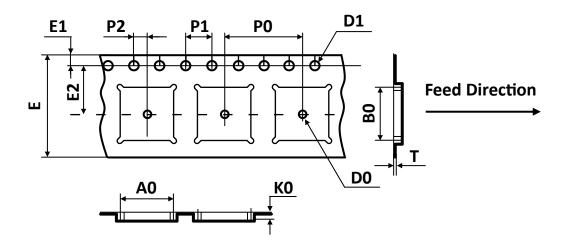


REEL DIMENSIONS All dimensions in mm



| Tape Size | Reel Size | М | Ν | т | Н | К | S |
|-----------|--------------|---------|---------|-------|-------|-------|-------|
| 12mm | Ø330 | Ø330.00 | Ø100.00 | 2.20 | 20.00 | 13.20 | 3.00 |
| 1211111 | \$550 | ±2.00 | ±0.50 | ±0.20 | ±1.00 | ±0.20 | ±1.00 |

TAPE DIMENSIONS All dimensions in mm



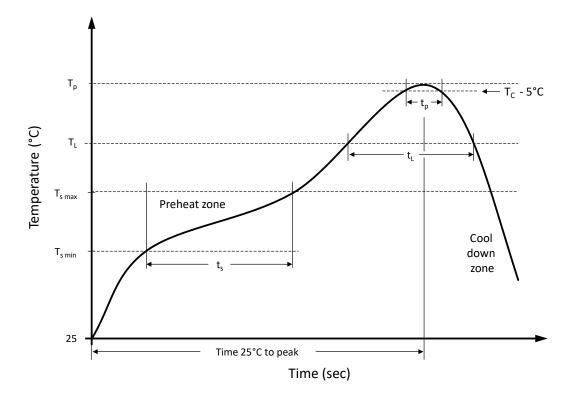
| Package | A0 | B0 | К0 | D0 | D1 | E | E1 | E2 | P0 | P1 | P2 | т |
|---------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| SO8 | 6.50 | 5.30 | 2.05 | 1.50 | 1.50 | 12.00 | 1.75 | 5.50 | 8.00 | 4.00 | 2.00 | 0.25 |
| 308 | ±0.10 | ±0.10 | ±0.15 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.05 | ±0.02 |

Note: All dimensions meet EIA-481-D requirements.





RECOMMENDED REFLOW SOLDERING PROFILE



Recommended reflow soldering conditions ▲ **Refer to JEDEC J-STD-020E**

| Profile Features | | Sn-Pb Eutetic Assembly | Pb-Free Assembly |
|--|-------------|------------------------|------------------|
| Preheat temperature min. | T_{smin} | 100 °C | 150 °C |
| Preheat temperature max. | $T_{s max}$ | 150 °C | 200 °C |
| Preheat time t_s from $T_{s min}$ to $T_{s max}$ | ts | 120 seconds | 120 seconds |
| Ramp-up rate (T _L to T _p) | | max. 3 °C/second | max. 3 °C/second |
| Liquidous temperature | ΤL | 183 °C | 217 °C |
| Time t_L maintained above T_L | t∟ | 150 seconds max. | 150 seconds max. |
| Peak package body temperature | Tp | 235°C | 260°C |
| Timeframe of within 5°C below and up to max actual peak body temperature | tp | 20 seconds max. | 30 seconds max. |
| Ramp-down rate (T_L to T_p) | | max. 6 °C/second | max. 6 °C/second |
| Time 25°C to peak temperature | | max. 6 minutes | max. 8 minutes |

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REVISION TABLE

| Revision | Date | Status | Notes |
|----------|------------|-----------------|---------------------|
| 001 | 30/09/2022 | Initial release | Initial publication |
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